

BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC4084$

J-FET INPUT QUAD OPERATIONAL AMPLIFIER

DESCRIPTION

The μ PC4084, is a quad operational amplifier incorporating well matched ion implant P-channel J-FET on the same chip with standard bipolar transistors. The key features of this op amp is very low input bias current and high slew rate ten times faster than conventional general purpose op amps. By these features μ PC4084, is excellent choice for wide variety of applications including integrator, active filter, pulse amp etc.

FEATURES

- Low noise: $e_n = 25 \text{ nV}/\sqrt{\text{Hz}}$ (TYP.)
- · Very low input bias and offset currents
- Output short circuit protection
- High input impedance...J-FET Input stage
- Internal frequency compensation
- High slew rate...13 V/μs (TYP.)

ORDERING INFORMATION

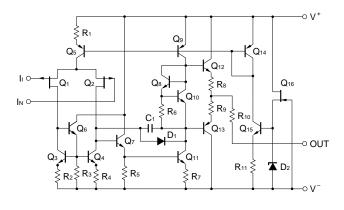
Part Number

Package

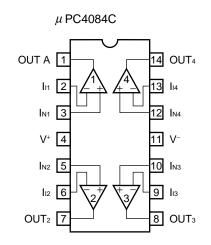
μPC4084C

14-pin plastic DIP (7.62 mm (300))

EQUIVALENT CIRCUIT



PIN CONFIGURATION (Top View)



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ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Voltage between V^+ and $V^{-Note 1}$	$V^+ - V^-$	-0.3 to +36	V
Differential Input Voltage	Vid	±30	V
Input Voltage ^{Note 2}	Vı	V ⁻ -0.3 to V ⁺ +0.3	V
Output Voltage ^{Note 3}	Vo	V ⁻ -0.3 to V ⁺ +0.3	V
Power Dissipation Note 4	Pτ	570	mW
Output Short Circuit Duration Note 5		Indefinite	sec
Operating Ambient Temperature	TA	-20 to +80	°C
Storage Temperature	Tstg	-55 to +125	°C

Notes 1. Reverse connection of supply voltage can cause destruction.

- 2. The input voltage should be allowed to input without damage or destruction. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The normal operation will establish when the both inputs are within the Common Mode Input Voltage Range of electrical characteristics.
- 3. This specification is the voltage which should be allowed to supply to the output terminal from external without damage or destructive. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The output voltage of normal operation will be the Output Voltage Swing of electrical characteristics.
- 4. Thermal derating factor is -7.6 mV/°C when operating ambient temperature is higher than 50°C.
- 5. Pay careful attention to the total power dissipation not to exceed the absolute maximum ratings, Note 4.

RECOMMENDED OPERATING CONDITIONS

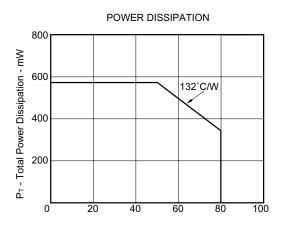
	Parameter	Symbol	MIN.	TYP.	MAX.	Unit
	Supply Voltage	V [±]	±5		±16	V
*	Output Current	lo			±10	mA
*	Capacitive Load (Av = +1, $R_f = 0 \Omega$)	CL			100	pF

ELECTRICAL CHARACTERISTICS (TA = 25°C, V^{\pm} = ±15 V)

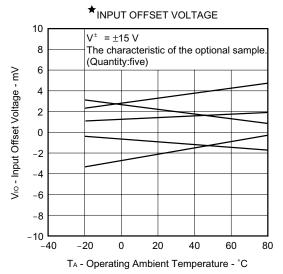
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input Offset Voltage	Vio	$R_{s} \le 50 \ \Omega$		±5	±15	mV
Input Offset Current Note 6	lio			±5	±200	pА
Input Bias Current Note 6	Ів			30	400	pА
Large Signal Voltage Gain	Av	$R_L \geq 2 \; k \Omega$, V_O = $\pm 10 \; V$	25000	200000		
Supply Current	lcc	Io = 0 A, All Amplifiers		8.0	11.2	mA
Common Mode Rejection Ratio	CMR		70	76		dB
Supply Voltage Rejection Ratio	SVR		70	76		dB
Output Voltage Swing	Vom	$R_L \ge 10 \ k\Omega$	±12	±13.5		V
		$R_L \ge 2 \ k\Omega$	±10	±12		V
Common Model Input Voltage Range	VICM		±10	+15		V
				-12.7		
Slew Rate	SR	A∨ = 1		13		V/µs
Unity Gain Frequency	funity			3		MHz
Input Equivalent Noise Voltage Density	en	Rs = 100 Ω, f = 1 kHz		25		nV/√Hz
Channel Separation				120		dB
Input Offset Voltage	Vio	$R_{S} \le 50 \ \Omega$, $T_{A} = -20$ to +70°C			±20	mV
Average VIO Temperature Drift	ΔVιο/ΔΤ	T _A = -20 to +70°C		±10		μV/°C
Input Offset Current	lio	T _A = -20 to +70°C			±5	nA
Input Bias Current ^{Note 6}	Ів	T _A = -20 to +70°C			10	nA

Notes 6. Input bias currents flow into IC. Because each currents are gate leak current of P-channel J-FET on input stage. And that are temperature sensitive. Short time measuring method is recommendable to maintain the junction temperature close to the operating ambient temperature.

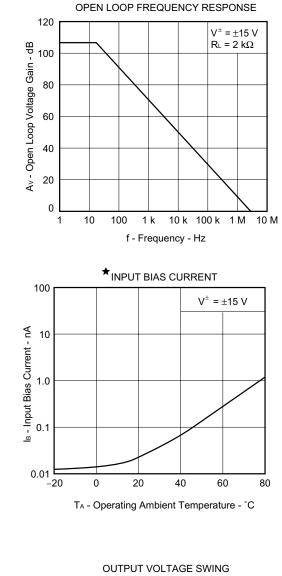
TYPICAL PERFORMANCE CHARACTERISTICS (TA = 25°C, TYP.)

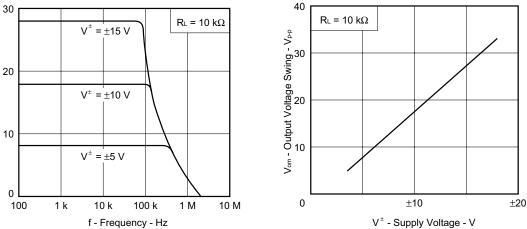






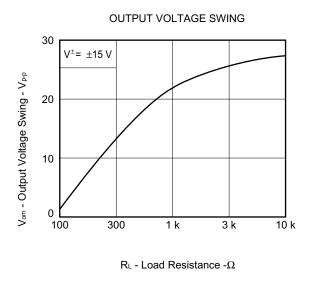
LARGE SIGNAL FREQUENCY RESPONSE

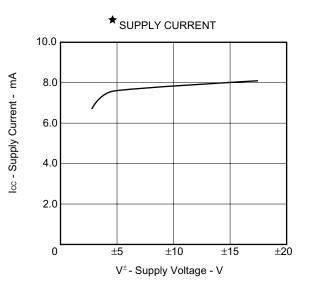


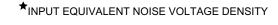


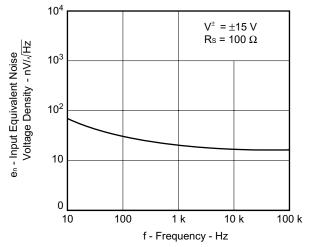
Data Sheet G15377EJ3V0DS

Vom - Output Voltage Swing - Vp-p

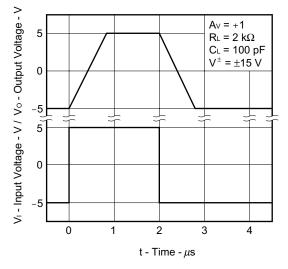






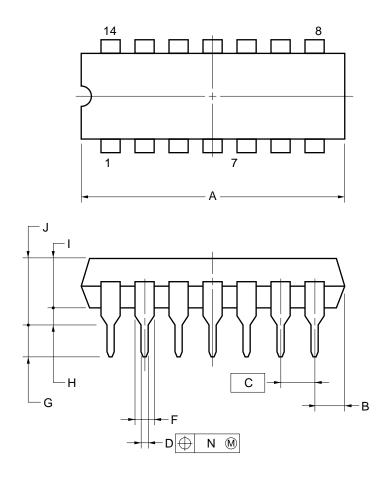


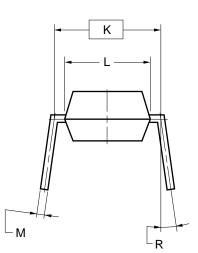
VOLTAGE FOLLOWER PULSE RESPONSE



* PACKAGE DRAWING (Unit : mm)

14-PIN PLASTIC DIP (7.62 mm (300))





NOTES

- 1. Each lead centerline is located within 0.25 mm of its true position (T.P.) at maximum material condition.
- 2. Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	
А	19.22±0.2	
В	2.14 MAX.	
С	2.54 (T.P.)	
D	0.50±0.10	
F	1.32±0.12	
G	3.6±0.3	
Н	0.51 MIN.	
I	3.55	
J	4.3±0.2	
К	7.62 (T.P.)	
L	6.4±0.2	
М	$0.25\substack{+0.10 \\ -0.05}$	
Ν	0.25	
R	0~15°	
P14C-100-300B1-3		

***** RECOMMENDED SOLDERING CONDITIONS

When soldering this product, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (C10535E).

Type of Through-hole Device

µPC4084C: 14-pin plastic DIP (7.62 mm (300))

Process	Conditions		
Wave Soldering (only to leads)	Solder temperature: 260°C or below, Flow time: 10 seconds or less.		
Partial Heating Method	Pin temperature: 300°C or below, Heat time: 3 seconds or less (per each lead).		

Caution For through-hole device, the wave soldering process must be applied only to leads, and make sure that the package body does not get jet soldered.

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